

74LVX14

Low Voltage Hex Inverter with Schmitt Trigger Input

General Description

The LVX14 contains six inverter gates each with a Schmitt trigger input. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. In addition, they have a greater noise margin than conventional inverters.

The LVX14 has hysteresis between the positive-going and negative-going input thresholds (typically 1.0V) which is determined internally by transistor ratios and is essentially insensitive to temperature and supply voltage variations.

The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

Features

- Input voltage level translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

Order Number	Package Number	Package Description
74LVX14M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74LVX14MX_NL	M14A	Pb-Free 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74LVX14SJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVX14MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74LVX14MTCX_NL (Note 1)	MTC14	Pb-Free 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

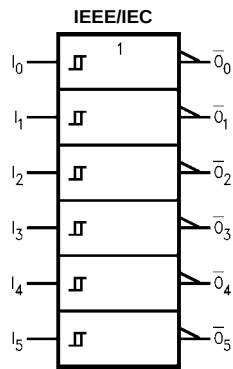
Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Pb-Free package per JEDEC J-STD-020B.

Note 1: " _NL" indicates Pb-Free package (per JEDEC J-STD-020B). Device available in Tape and Reel only.

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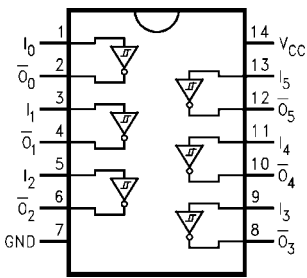
Logic Symbol



Pin Descriptions

Pin Names	Description
I_n	Inputs
$\bar{O}_n$	Outputs

Connection Diagram



Truth Table

Input	Output
A	$\bar{O}$
L	H
H	L

Absolute Maximum Ratings(Note 2)

Supply Voltage (V_{CC})	-0.5V to +7.0V
DC Input Diode Current (I_{IK})	
$V_I = -0.5V$	-20 mA
DC Input Voltage (V_I)	-0.5V to 7V
DC Output Diode Current (I_{OK})	
$V_O = -0.5V$	-20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V_O)	-0.5V to $V_{CC} + 0.5V$
DC Output Source	
or Sink Current (I_O)	± 25 mA
DC V_{CC} or Ground Current	
(I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	-65°C to +150°C
Power Dissipation	180 mW

Recommended Operating Conditions (Note 3)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to 5.5V
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	-40°C to +85°C

Note 2: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC}	$T_A = +25^\circ\text{C}$			$T_A = -40^\circ\text{C to } +85^\circ\text{C}$		Units	Conditions	
			Min	Typ	Max	Min	Max			
V_{T+}	Positive Threshold	3.0			2.2		2.2	V		
V_{T-}	Negative Threshold	3.0	0.9			0.9		V		
V_H	Hysteresis	3.0	0.3		1.2	0.3	1.2	V		
V_{OH}	HIGH Level	2.0	1.9	2.0		1.9		V	$V_{IN} = V_{IL} \text{ or } V_{IH}$	$I_{OH} = -50 \mu\text{A}$
	Output Voltage	3.0	2.9	3.0		2.9				$I_{OH} = -50 \mu\text{A}$
		3.0	2.58			2.48				$I_{OH} = -4 \text{ mA}$
V_{OL}	LOW Level	2.0		0.0	0.1		0.1	V	$V_{IN} = V_{IL} \text{ or } V_{IH}$	$I_{OL} = 50 \mu\text{A}$
	Output Voltage	3.0		0.0	0.1		0.1			$I_{OL} = 50 \mu\text{A}$
		3.0			0.36		0.44			$I_{OL} = 4 \text{ mA}$
I_{IN}	Input Leakage Current	3.6			± 0.1		± 1.0	μA	$V_{IN} = 5.5V \text{ or GND}$	
I_{CC}	Quiescent Supply Current	3.6			2.0		20	μA	$V_{IN} = V_{CC} \text{ or GND}$	

Noise Characteristics (Note 4)

Symbol	Parameter	V_{CC} (V)	$T_A = 25^\circ\text{C}$		Units	C_L (pF)
			Typ	Limit		
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.3	0.5	V	50
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	-0.3	-0.5	V	50
V_{IHD}	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	3.3		0.8	V	50

Note 4: Input $t_r = t_f = 3\text{ns}$

AC Electrical Characteristics

Symbol	Parameter	V _{CC} (V)	T _A = +25°C			T _A = -40°C to +85°C		Units	C _L (pF)
			Min	Typ	Max	Min	Max		
t _{PLH}	Propagation	2.7		8.7	16.3	1.0	19.5	ns	15
t _{PHL}	Delay Time			11.2	19.8	1.0	23.0		50
		3.3 ± 0.3		6.8	10.6	1.0	12.5		15
				9.3	14.1	1.0	16.0		50
t _{OSLH}	Output to Output	2.7			1.5		1.5	ns	50
t _{OSHL}	Skew (Note 5)	3.3			1.5		1.5		

Note 5: Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

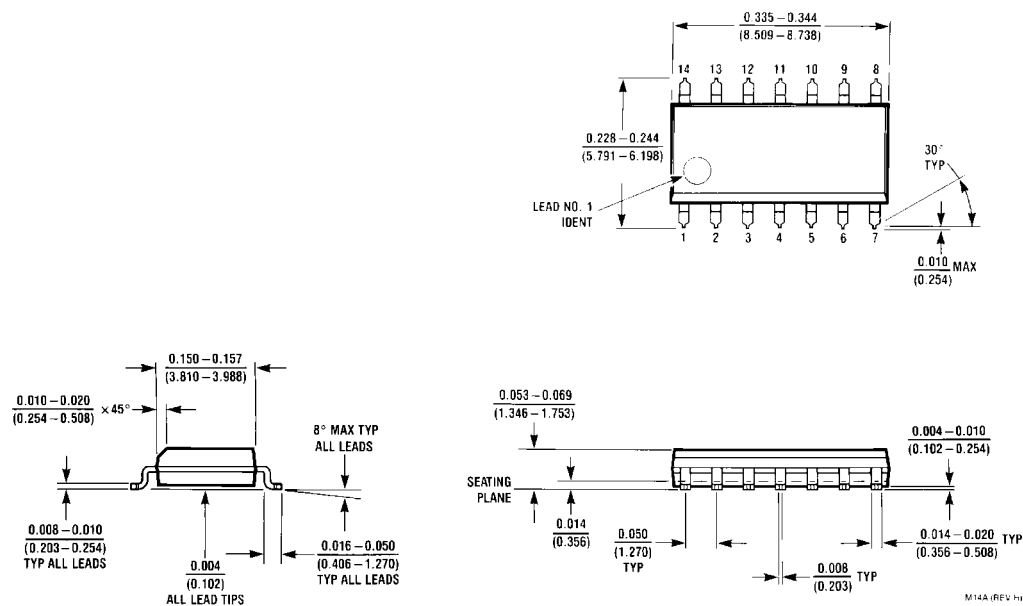
Capacitance

Symbol	Parameter	T _A = +25°C			T _A = -40°C to +85°C		Units
		Min	Typ	Max	Min	Max	
C _{IN}	Input Capacitance		4	10		10	pF
C _{PD}	Power Dissipation Capacitance (Note 6)		21				pF

Note 6: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

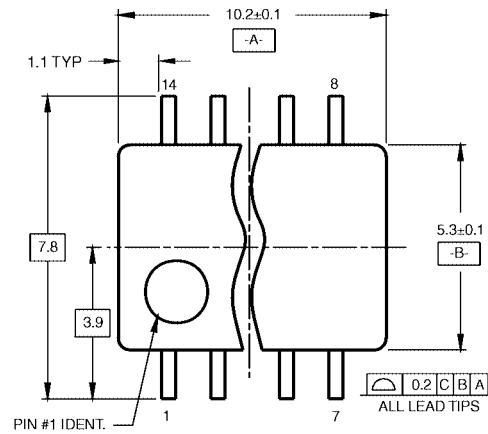
$$\text{Average operating current can be obtained by the equation: } I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{6 \text{ (per Gate)}}$$

Physical Dimensions inches (millimeters) unless otherwise noted

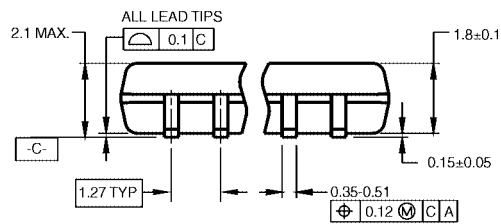


**14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
Package Number M14A**

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



LAND PATTERN RECOMMENDATION



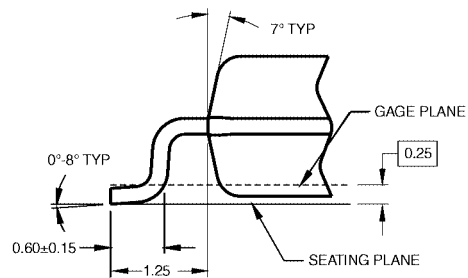
DIMENSIONS ARE IN MILLIMETERS



NOTES:

- A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

M14DRevB1



DETAIL A

**Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D**

